Revision. 1

Zener Diode

DZ2605100L

Panasonic

DZ2605100L

Silicon epitaxial planar type

For constant voltage / For surge absorption circuit DZ27051 in ML2 type package

■ Features

- Excellent rising characteristics of zener current IZ
- Low zener operating resistance RZ
- Halogen-free / RoHS compliant
 (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol : CJ

■ Packaging

Embossed type (Thermo-compression sealing) 10 000 pcs / reel (standard)

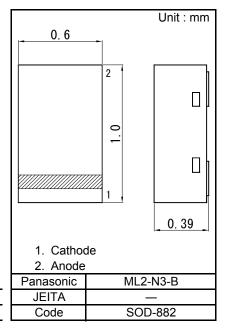
■ Absolute Maximum Ratings Ta = 25 °C

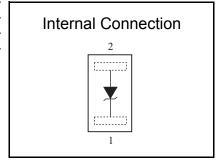
Parameter	Symbol	Rating	Unit
Repetitive peak forward current	IFRM	200	mA
Total power dissipation *1	PT	100	mW
Electrostatic discharge *2	ESD	±15	kV
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

Note) *1 PT = 100 mW achieved with a printed circuit board.

*2 Test method:IEC61000_4_2

(C = 150 pF , R = 330 Ω , Contact discharge : 10 times)





■ Electrical Characteristics Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	VF	IF = 10 mA			1.0	V
Zener voltage *1, *2	VZ	IZ = 5 mA	4.85		5.36	V
Zener operating resistance	RZ	IZ = 5 mA			60	Ω
Zener rise operating resistance	RZK	IZ = 1 mA			500	Ω
Reverse current	IR	VR = 2.0 V			1.0	μΑ
Temperature coefficient of zener voltage *3	SZ	IZ = 5 mA		0.7		mV/°C

- Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 Measuring methods for Diodes.
 - 2. Absolute frequency of input and output is 5 MHz.
 - 3. *1 The temperature must be controlled 25 °C for VZ mesurement. VZ value measured at other temperature must be adjusted to VZ (25 °C)
 - *2 VZ guaranteed 20 ms after current flow.
 - *3 Tj = 25 °C to 150 °C

Established: 2013-04-03

Revised

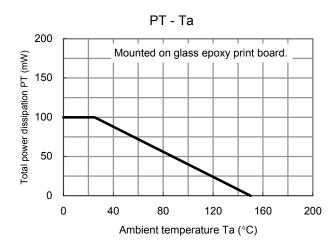
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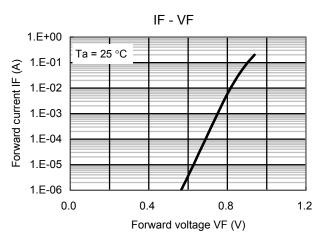
Zener Diode

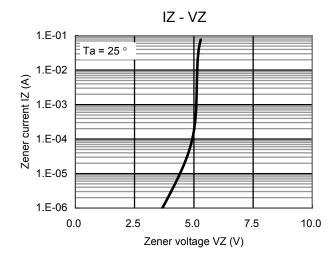
DZ2605100L

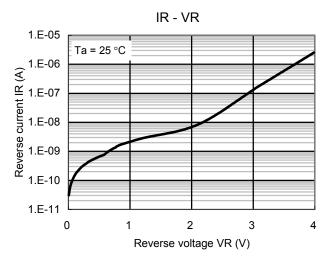
Panasonic

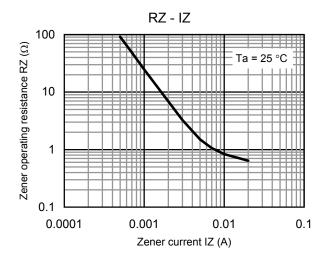
Technical Data (reference)

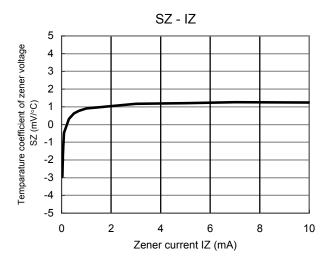










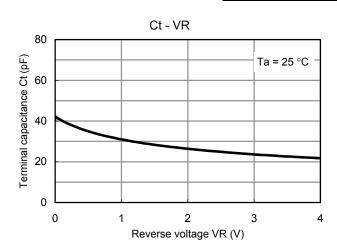


Established : 2013-04-03 Revised : ###-## **Panasonic**

Zener Diode

DZ2605100L

Technical Data (reference)



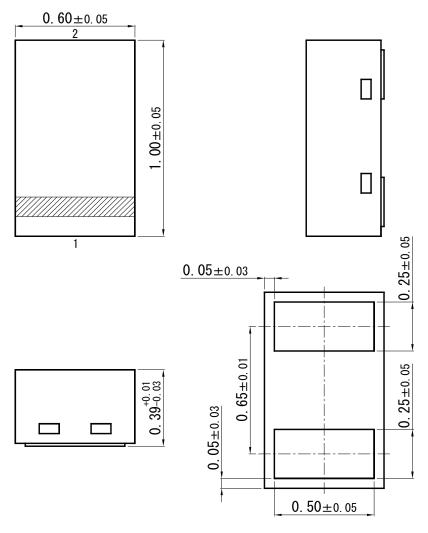
Established : 2013-04-03 Revised : ###-##-##

Zener Diode

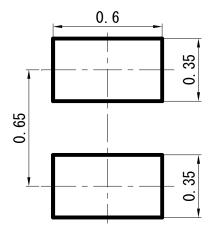
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ML2-N3-B Unit: mm



■ Land Pattern (Reference) (Unit: mm)



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